APPLN. FILING DATE: JANUARY 24, 2002
TITLE HEAT DISSIPATION TYPE SEMICONDUCTOR
INVESTIGATION SUN KIM
APPLICATION SUN KIM
APPLICATION SUN KIM

APPLICATION SERIAL NO: 033526-001

SHEET 1 of 4

1/4 FIG. 1

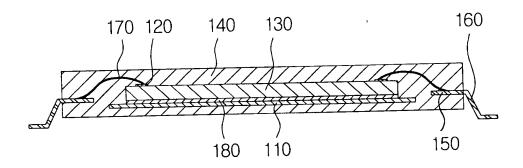


FIG. 2

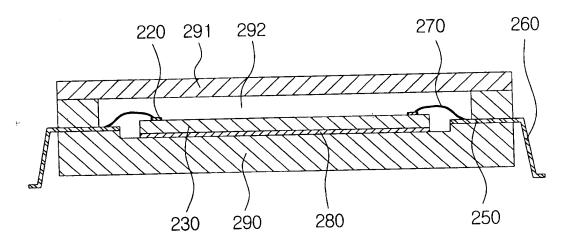
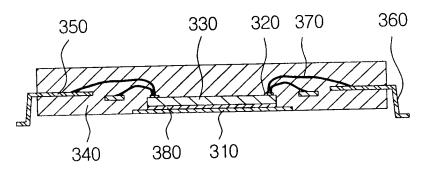


FIG. 3



APPLN. FILING DATE: JANUARY 24, 2002

TITY HEAT DISSIPATION TYPE SEMICONDUCTOR 10 / 031853

INVENE PROPERTY OF THE PROPERTY OF

2/4 FIG. 4

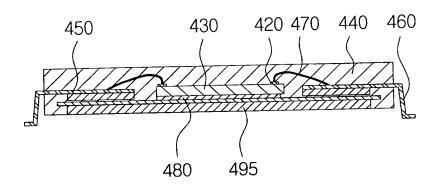


FIG. 5A

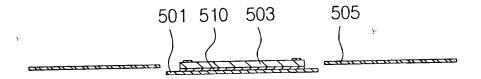
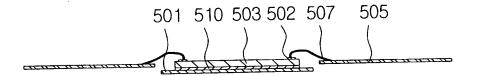
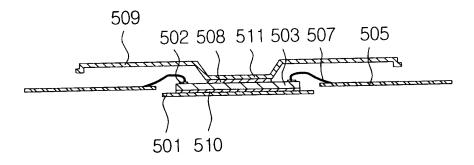


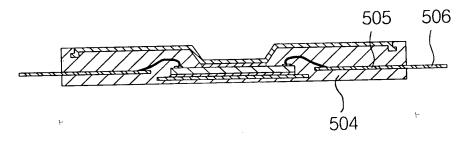
FIG. 5B



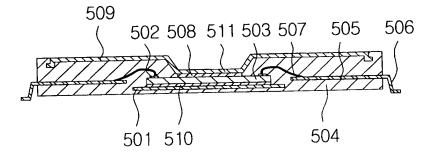
## 3/4 FIG. 5C



## FIG. 5D



## FIG. 5E



APPLN. FILING DATE: JANUARY 24, 2002
TIME: HEAT DISSIPATION TYPE SEMICONDUCT
INTOR(S): YOUNG SUN KIM
APPLICATION SERIAL NO: 033526-001
SHEET 4 of 4

4/4 FIG. 5F

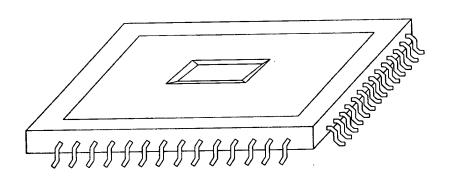


FIG. 6

